

2.5V CMOS DUAL 1-TO-5 CLOCK DRIVER

IDT49FCT20805

FEATURES:

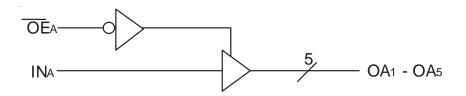
- · Advanced CMOS Technology
- Guaranteed low skew < 200ps (max.)
- Very low propagation delay < 2.5ns (max)
- Very low duty cycle distortion < 270ps (max)
- Very low CMOS power levels
- · Operating frequency up to 166MHz
- TTL compatible inputs and outputs
- · Two independent output banks with 3-state control
- 1:5 fanout per bank
- · "Heartbeat" monitor output
- $VCC = 2.5V \pm 0.2V$
- · Available in SSOP and QSOP packages

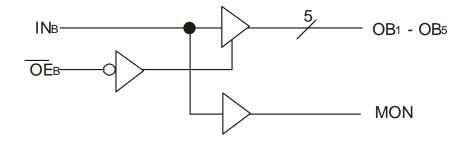
DESCRIPTION:

The FCT20805 is a 2.5 volt clock driver built using advanced CMOS technology. The device consists of two banks of drivers, each with a 1:5 fanout and its own output enable control. The device has a "heartbeat" monitor for diagnostics and PLL driving. The MON output is identical to all other outputs and complies with the output specifications in this document. The FCT20805 offers low capacitance inputs.

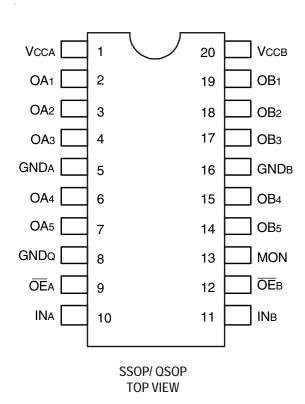
The FCT20805 is designed for high speed clock distribution where signal quality and skew are critical. The FCT20805 also allows single point-to-point transmission line driving in applications such as address distribution, where one signal must be distributed to multiple recievers with low skew and high signal quality.

FUNCTIONAL BLOCK DIAGRAM





PIN CONFIGURATIONS



ABSOLUTE MAXIMUM RATINGS(1)

Symbol	Description	Max	Unit
Vcc	Input Power Supply Voltage	-0.5 to +4.6	V
Vı	InputVoltage	-0.5 to +5.5	V
Vo	Output Voltage	-0.5 to Vcc+0.5	V
TJ	Junction Temperature	150	°C
Tstg	Storage Temperature	-65 to +165	°C

NOTE:

Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause
permanent damage to the device. This is a stress rating only and functional operation
of the device at these or any other conditions above those indicated in the operational
sections of this specification is not implied. Exposure to absolute maximum rating
conditions for extended periods may affect reliability.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

	,	•			
Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	3	4	pF
Соит	Output Capacitance	Vout = 0V	_	6	рF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names	Description
OEA, OEB	3-State Output Enable Inputs (Active LOW)
INA, INB	Clock Inputs
OAn, OBn	Clock Outputs
MON	MonitorOutput

FUNCTION TABLE (1)

Inpi	uts	Outputs		
OEA, OEB	INA, INB	OAn, OBn	MON	
L	L	L	L	
L	Н	Н	Н	
Н	L	Z	L	
Н	Н	Z	Н	

NOTE:

- 1. H = HIGH
 - L = LOW
 - Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified Industrial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 2.5V \pm 0.2V$

Symbol	Parameter	Test Cond	tions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
VIH	Input HIGH Level			1.7	_	5.5	V
VIL	Input LOW Level			-0.5	_	0.7	V
Іін	Input HIGH Current	Vcc = Max.	Vı = 5.5V	_	_	±1	
lıL	Input LOW Current	Vcc = Max.	Vı = GND	_	_	±1	μΑ
lozh	High Impedance Output Current	Vcc = Max.	Vo = Vcc	_	_	±1]
lozl	(3-State Outputs Pins)		Vo = GND	_	_	±1]
VIK	Clamp Diode Voltage	Vcc = Min., IIN = -18mA	Vcc = Min., lin = -18mA		-0.7	-1.2	V
IODH	Output HIGH Current	Vcc = 2.5V, Vin = Vih or Vil	$Vo = 1.25V^{(3,4)}$	-15	-35	-90	mA
IODL	Output LOW Current	Vcc = 2.5V, Vin = Vih or Vil	., Vo = 1.25V ^(3,4)	25	55	100	mA
los	Short Circuit Current	Vcc = Max., Vo = GND(3,4)		-30	-50	-120	mA
Vон	Output HIGH Voltage	Vcc = Min.	Iон = -8mA	1.7 ⁽⁵⁾	_	_	V
		VIN = VIH or VIL	Іон = –100μА	Vcc-0.2	_	_	
Vol	Output LOW Voltage	Vcc = Min.	IoL = 8mA	_	0.2	0.4	V
		VIN = VIH or VIL	IoL = 100μA	_	_	0.2]

NOTES:

- 1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 2.5V, 25°C ambient.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. This parameter is guaranteed but not tested.
- 5. VoH = Vcc -0.6V at rated current.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Con	ditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Unit
ICCL ICCH ICCZ	Quiescent Power Supply Current	Vcc = Max. Vin = GND or Vcc		_	0.1	20	μА
Δlcc	Power Supply Current per Input HIGH	Vcc = Max. Vin = Vcc -0.6V		_	35	250	μΑ
ICCD	Dynamic Power Supply Current per Output ⁽³⁾	Vcc = Max. CL = 15pF All Outputs Toggling	VIN = VCC VIN = GND	_	65	100	µA/MHz
Ic	Total Power Supply Current ⁽⁴⁾	Vcc = Max. CL = 15pF	VIN = VCC VIN = GND	_	100	125	
		All Outputs Toggling fi = 133MHz	VIN = VCC -0.6V VIN = GND	_	100	125	mA
		Vcc = Max. CL = 15pF	VIN = VCC VIN = GND	_	115	150	
		All Outputs Toggling fi = 166MHz	VIN = VCC -0.6V VIN = GND	_	115	150	

NOTES:

- 1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at Vcc = 2.5V, +25°C ambient.
- 3. This parameter is not directly testable, but is derived for use in Total Power Supply calculations.
- 4. IC = IQUIESCENT + INPUTS + IDYNAMIC
 - $Ic = Icc + \Delta Icc DhNT + Icco (foNo)$
 - Icc = Quiescent Current (IccL, IccH and Iccz)
 - Δ Icc = Power Supply Current for a TTL High Input (VIN = Vcc -0.6V)
 - DH = Duty Cycle for TTL Inputs High
 - NT = Number of TTL Inputs at DH
 - ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)
 - fo = Output Frequency
 - No = Number of Outputs at fo

SWITCHING CHARACTERISTICS OVER OPERATING RANGE (3,4)

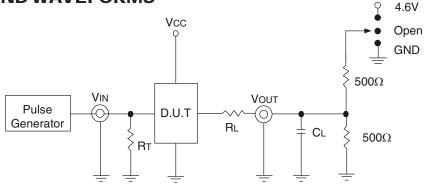
Symbol	Parameter	Conditions ⁽¹⁾	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay	CL = 15pF	1	3	ns
tPHL	INA to OAn, INB to OBn	f≤133MHz			
t R	Output Rise Time (0.8V to 2V)		_	1.5	ns
tF	Output Fall Time (2V to 0.8V)			1.5	ns
tsk(o)	Same device output pin to pin skew ⁽⁵⁾		_	270	ps
tsk(P)	Pulse skew ^(6,9)		_	270	ps
tsk(PP)	Part to part skew ⁽⁷⁾		_	550	ps
tPZL	Output Enable Time		_	5.2	ns
tpzh	OEA to OAn, OEB to OBn				
tPLZ	Output Disable Time		_	5.2	ns
tPHZ	OEA to OAn, OEB to OBn				
fMAX	InputFrequency		_	133	MHz

Symbol	Parameter	Conditions ^(1,8)	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay	CL = 15pF	0.5	2.5	ns
tPHL	INA to OAn, INB to OBn	133MHz ≤ f ≤ 166MHz			
t R	Output Rise Time (0.7V to 1.7V)		_	1.25	ns
tF	Output Fall Time (1.7V to 0.7V)		_	1.25	ns
tsk(0)	Same device output pin to pin skew ⁽⁵⁾		_	200	ps
tsk(P)	Pulse skew ^(6,9)		_	270	ps
tsk(PP)	Part to part skew ⁽⁷⁾		_	550	ps
tpzl	Output Enable Time		_	5.2	ns
t PZH	OEA to OAn, OEB to OBn				
tPLZ	Output Disable Time		_	5.2	ns
t PHZ	OEA to OAn, OEB to OBn				
fMAX	Input Frequency		_	166	MHz

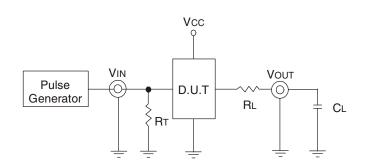
NOTES:

- 1. See test circuits and waveforms.
- 2. Minimum limits are guaranteed but not tested on Propagation Delays.
- 3. tplh and tphl are production tested. All other parameters guaranteed but not production tested.
- 4. Propagation delay range indicated by Min. and Max. limit is due to Vcc, operating temperature and process parameters. These propagation delay limits do not imply skew.
- 5. Skew measured between all outputs under identical transitions and load conditions.
- 6. Skew measured is difference between propagation delay times tphL and tpLH of same outputs under identical load conditions.
- 7. Part to part skew for all outputs given identical transitions and load conditions at identical Vcc levels and temperature.
- 8. Airflow of 1m/s is recommended for frequencies above 133MHz.
- 9. This parameter is measured using f = 1MHz.

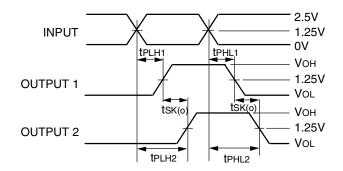
TEST CIRCUITS AND WAVEFORMS



Enable and Disable Time Circuit



CL = 15pF Test Circuit



tsk(o) = |tplh2 - tplh1| or |tphl2 - tphl1|

Output Skew - tsk(0)

SWITCH POSITION

Test	Switch
Disable Low Enable Low	4.6V
Disable High Enable High	GND

TEST CONDITIONS

Symbol	$Vcc = 2.5V \pm 0.2V$	Unit
CL	15	pF
Rт	Zout of pulse generator	Ω
RL	33	Ω
tr/tr	1 (0V to 2.5V or 2.5V to 0V)	ns

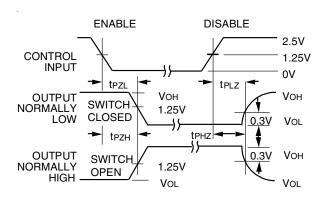
DEFINITIONS:

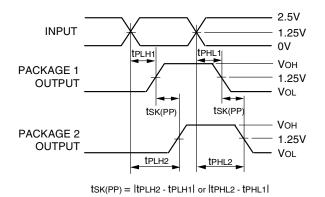
CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

 $t_R / t_F = Rise/Fall$ time of the input stimulus from the Pulse Generator.

TEST CIRCUITS AND WAVEFORMS

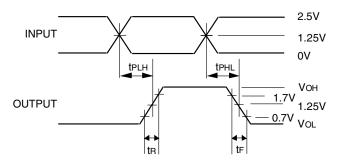




Enable and Disable Times

NOTE:

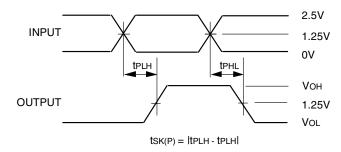
1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH



Propagation Delay

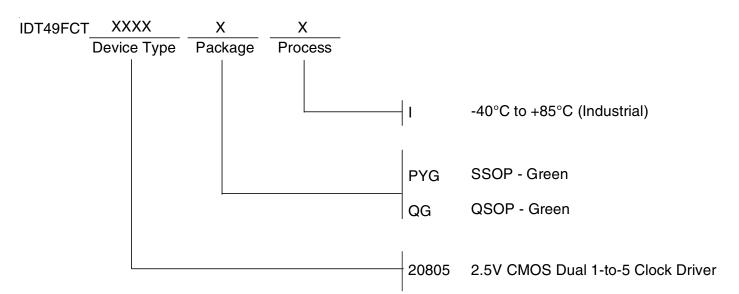
Part-to-Part Skew - tsk(PP)

Part-to-Part Skew is for the same package and speed grade.



Pulse Skew

ORDERING INFORMATION



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